NSN 5961-01-020-1669

Transistor - Page 1 of 1



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Overall	Laiabte	
Overan	Height:	

Between 0.320 inches and 0.468 inches

Internal Configuration:

Junction contact

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.423 inches and 0.438 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 125.0 collector to emitter voltage/static/base open and 20.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 25.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: npn

Test Data Document:

82577-928482 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0